

General Purpose Transistors

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PNP Silicon

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-323/SC-70 which is designed for low power surface mount applications.

Features

Pb- Free Package May be Available. The G.Suffix Denotes a Pb- Free Lead Finish

MAXIMUM RATINGS

Rating	Symbol	BC856	BC857	BC858	Unit
Collector-Emitter Voltage	V_{CEO}	-65	-45	-30	V
Collector-Base Voltage	V_{CBO}	-80	-50	-30	V
Emitter-Base Voltage	V_{EBO}	-5.0	-5.0	-5.0	V
Collector Current — Continuous	I_C	-100	-100	-100	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (1) $T_A = 25^\circ\text{C}$	P_D	150	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	833	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

DEVICE MARKING

LBC856AWT1 = 3A; LBC856BWT1 = 3B; LBC857AWT1 = 3E; LBC857BWT1 = 3F;
LBC858AWT1 = 3J; LBC858BWT1 = 3K; LBC858CWT1 = 3L

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

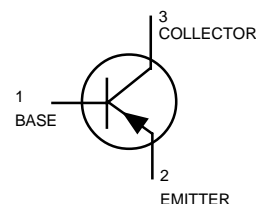
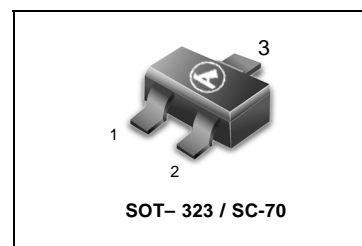
Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ($I_C = -10\text{ mA}$)	LBC856 Series	$V_{(BR)CEO}$	-65	—	—	v
	LBC857 Series		-45	—	—	
	LBC858 Series		-30	—	—	
Collector-Emitter Breakdown Voltage ($I_C = -10\ \mu\text{A}, V_{EB} = 0$)	LBC856 Series	$V_{(BR)CES}$	-80	—	—	v
	LBC857 Series		-50	—	—	
	LBC858 Series		-30	—	—	
Collector-Base Breakdown Voltage ($I_C = -10\ \mu\text{A}$)	LBC856 Series	$V_{(BR)CBO}$	-80	—	—	v
	LBC857 Series		-50	—	—	
	LBC858 Series		-30	—	—	
Emitter-Base Breakdown Voltage ($I_E = -1.0\ \mu\text{A}$)	LBC856 Series	$V_{(BR)EBO}$	-5.0	—	—	v
	LBC857 Series		-5.0	—	—	
	LBC858 Series		-5.0	—	—	
Collector Cutoff Current ($V_{CB} = -30\text{ V}$) ($V_{CB} = -30\text{ V}, T_A = 150^\circ\text{C}$)		I_{CBO}	—	—	-15	nA
			—	—	-4.0	μA

1.FR-5=1.0 x 0.75 x 0.062in

LBC856AWT1, BWT1
LBC857AWT1, BWT1
LBC858AWT1, BWT1
CWT1



LBC856AWT1, BWT1 LBC857AWT1, BWT1 LBC858AWT1, BWT1, CWT1

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
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ON CHARACTERISTICS

DC Current Gain ($I_C = -10\ \mu\text{A}$, $V_{CE} = -5.0\ \text{V}$)	LBC856A, LBC857A, LBC858A	h_{FE}	—	90	—	—
	LBC856B, LBC857B, LBC858B		—	150	—	
	LBC858C,		—	270	—	
($I_C = -2.0\ \text{mA}$, $V_{CE} = -5.0\ \text{V}$)	LBC856A, LBC857A, LBC858A		125	180	250	
	LBC856B, LBC857B, LBC858B		220	290	475	
	LBC858C,		420	520	800	
Collector–Emitter Saturation Voltage ($I_C = -10\ \text{mA}$, $I_B = -0.5\ \text{mA}$) ($I_C = -100\ \text{mA}$, $I_B = -5.0\ \text{mA}$)		$V_{CE(sat)}$	—	—	-0.3	V
			—	—	-0.65	
Base–Emitter Saturation Voltage ($I_C = -10\ \text{mA}$, $I_B = -0.5\ \text{mA}$) ($I_C = -100\ \text{mA}$, $I_B = -5.0\ \text{mA}$)		$V_{BE(sat)}$	—	-0.7	—	V
			—	-0.9	—	
Base–Emitter Voltage ($I_C = -2.0\ \text{mA}$, $V_{CE} = -5.0\ \text{V}$) ($I_C = -10\ \text{mA}$, $V_{CE} = -5.0\ \text{V}$)		$V_{BE(on)}$	-0.6	—	-0.75	V
			—	—	-0.82	

SMALL–SIGNAL CHARACTERISTICS

Current–Gain — Bandwidth Product ($I_C = -10\ \text{mA}$, $V_{CE} = -5.0\ \text{Vdc}$, $f = 100\ \text{MHz}$)	f_T	100	—	—	MHz
Output Capacitance ($V_{CB} = -10\ \text{V}$, $f = 1.0\ \text{MHz}$)	C_{ob}	—	—	4.5	pF
Noise Figure ($I_C = -0.2\ \text{mA}$, $V_{CE} = -5.0\ \text{Vdc}$, $R_S = 2.0\ \text{k}\Omega$, $f = 1.0\ \text{kHz}$, $BW = 200\ \text{Hz}$)	NF	—	—	10	dB

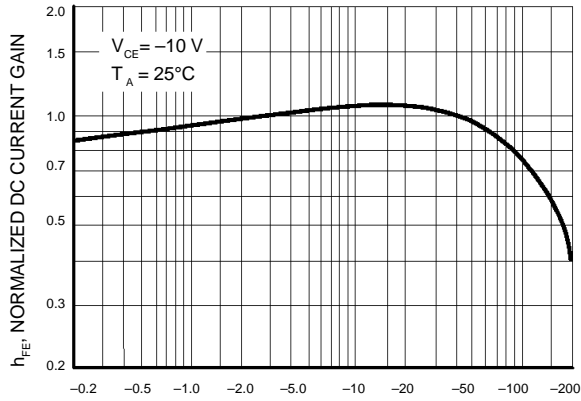
ORDERING INFORMATION (Pb–Free)

Device	Package	Shipping
LBC856AWT1G, BWT1G	SOT-23	3000/Tape & Reel
LBC857AWT1G, BWT1G	SOT-23	3000/Tape & Reel
LBC858AWT1G, BWT1G, CWT1G	SOT-23	3000/Tape & Reel

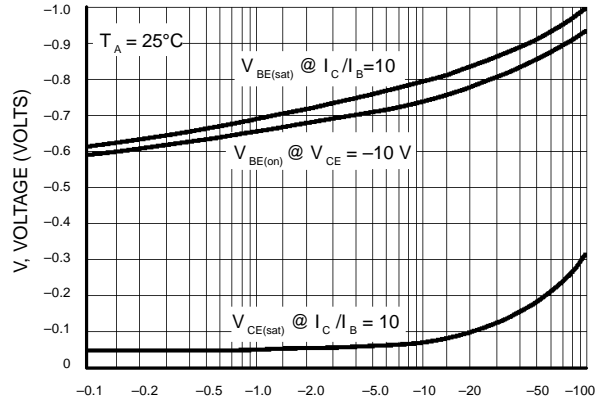
LBC856AWT1, BWT1 LBC857AWT1, BWT1, LBC858AWT1, BWT1, CWT1

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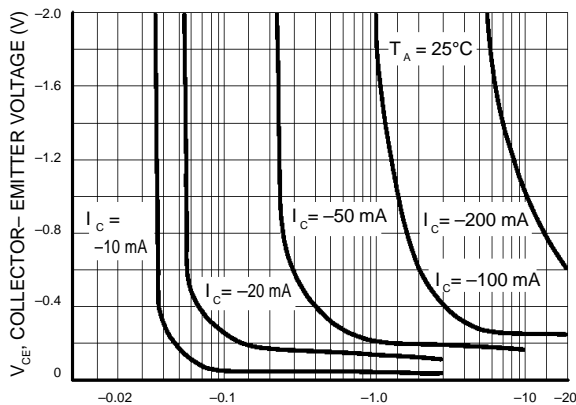
LBC857/LBC858



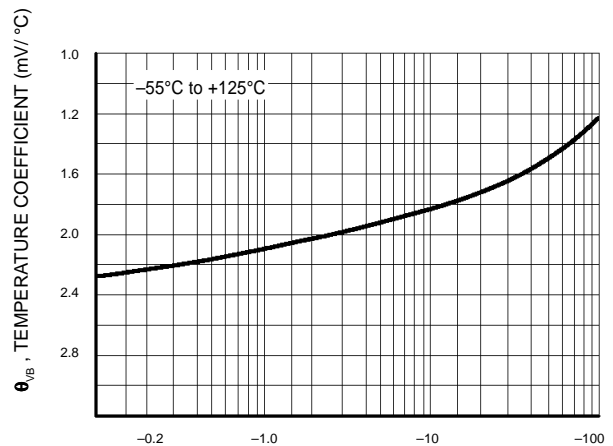
I_C , COLLECTOR CURRENT (mA)
Figure 1. Normalized DC Current Gain



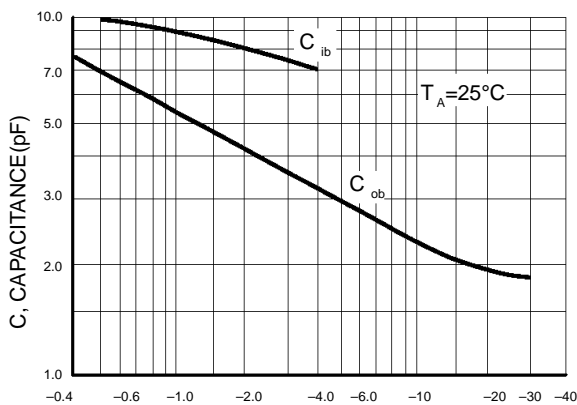
I_C , COLLECTOR CURRENT (mA)
Figure 2. "Saturation" and "On" Voltages



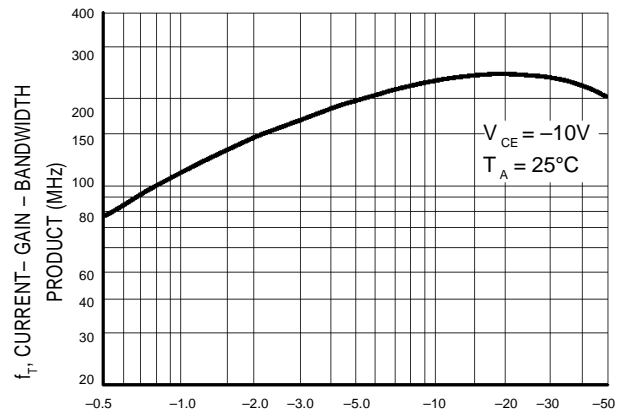
I_B , BASE CURRENT (mA)
Figure 3. Collector Saturation Region



I_C , COLLECTOR CURRENT (mA)
Figure 4. Base-Emitter Temperature Coefficient



V_R , REVERSE VOLTAGE (VOLTS)
Figure 5. Capacitances



I_C , COLLECTOR CURRENT (mA)
Figure 6. Current-Gain - Bandwidth Product

LBC856AWT1, BWT1 LBC857AWT1, BWT1, LBC858AWT1, BWT1, CWT1

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LBC856

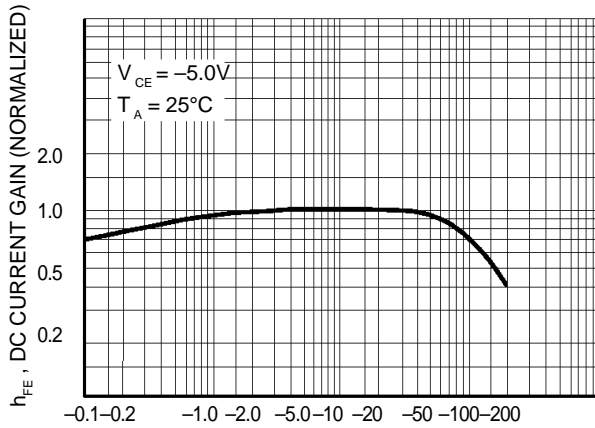


Figure 7. DC Current Gain

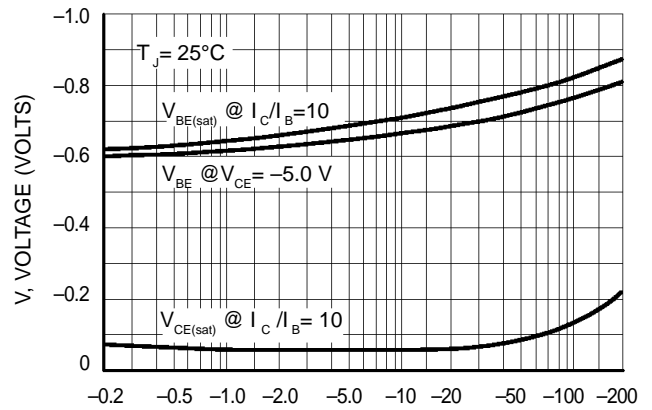


Figure 8. "On" Voltage

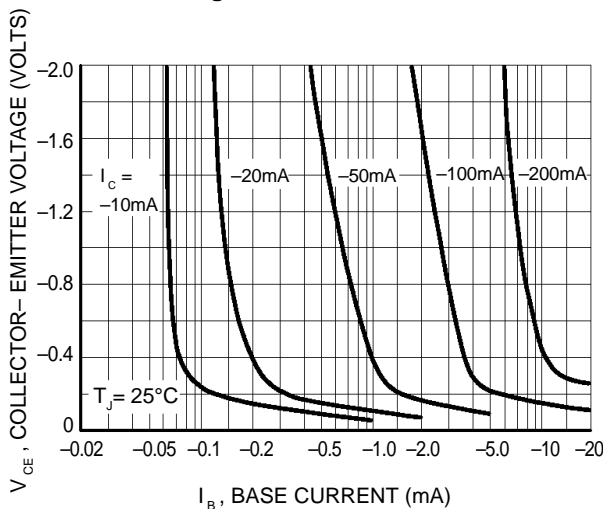


Figure 9. Collector Saturation Region

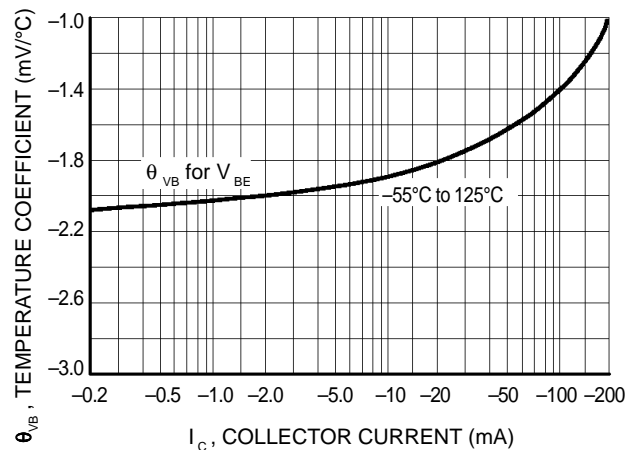


Figure 10. Base-Emitter Temperature Coefficient

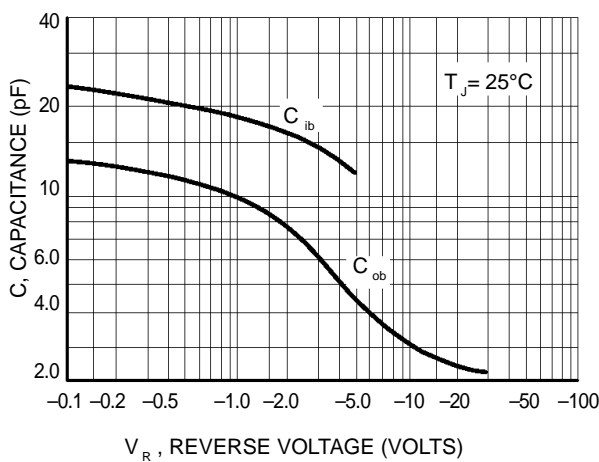


Figure 11. Capacitance

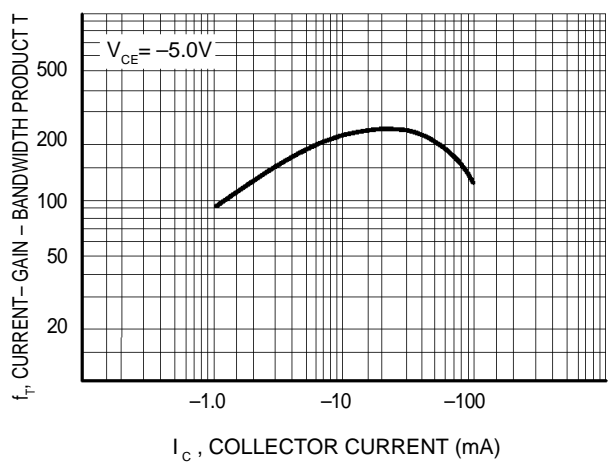


Figure 12. Current-Gain - Bandwidth Product

LBC856AWT1, BWT1 LBC857AWT1, BWT1, LBC858AWT1, BWT1, CWT1

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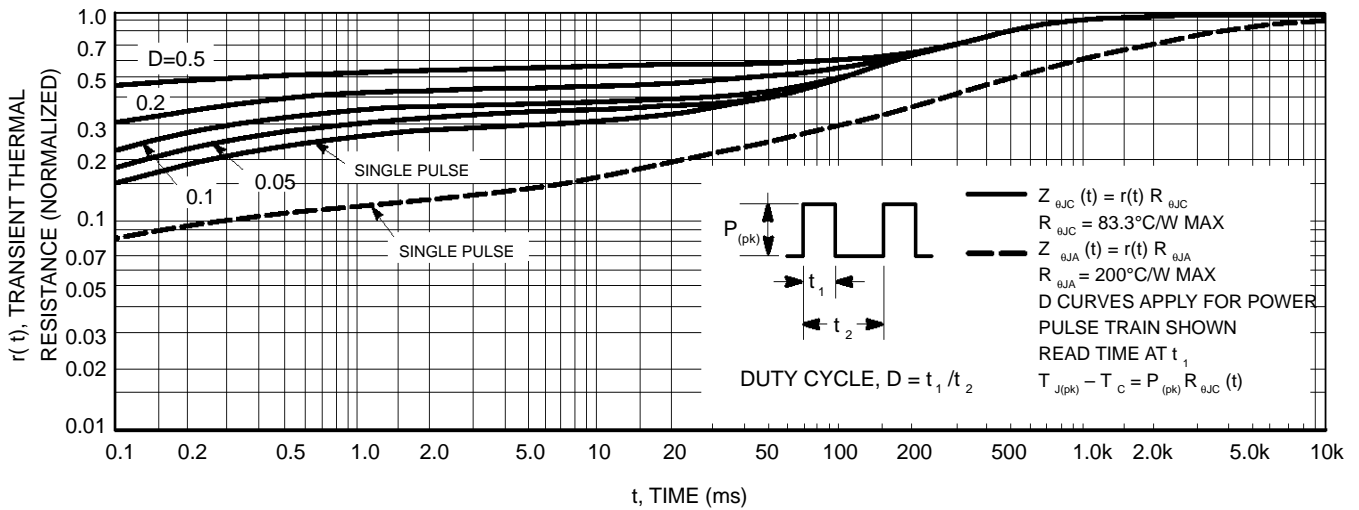


Figure 13. Thermal Response

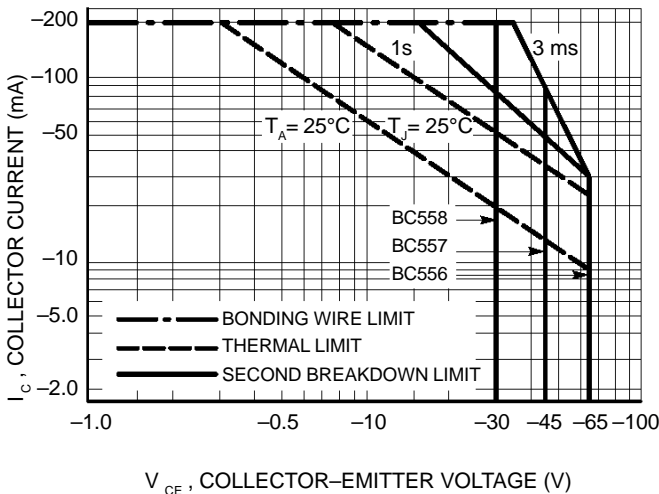


Figure 14. Active Region Safe Operating Area

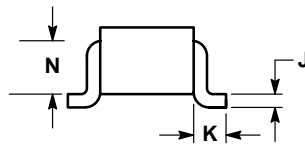
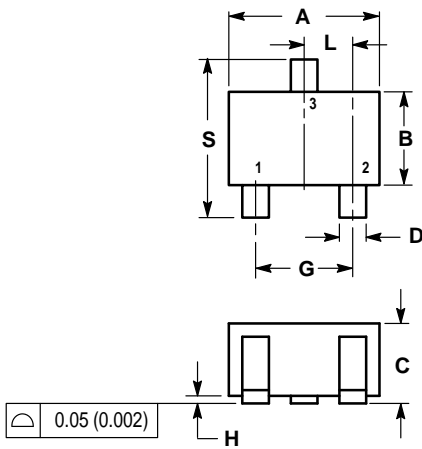
The safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 14 is based upon $T_{J(pk)} = 150^\circ\text{C}$; T_C or T_A is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^\circ\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

SC-70 / SOT-323

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.032	0.040	0.80	1.00
D	0.012	0.016	0.30	0.40
G	0.047	0.055	1.20	1.40
H	0.000	0.004	0.00	0.10
J	0.004	0.010	0.10	0.25
K	0.017 REF		0.425 REF	
L	0.026 BSC		0.650 BSC	
N	0.028 REF		0.700 REF	
S	0.079	0.095	2.00	2.40

- PIN 1. BASE
 2. EMITTER
 3. COLLECTOR

